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	Filing Date		2004-12-17	
	First Named Inventor	Shi Xue Dou		
	Art Unit	1796		
	Examiner Name	Mark T. Kopec		
	Attorney Docket Number	7383-83836		

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4	02-129812	JP	A	1990-05-17	JGC Corp	<input checked="" type="checkbox"/>
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	1	ZHAO, Y. et al., High Critical Current Density of MgB <sub>2</sub> Bulk Superconductor Doped with Ti and sintered at ambient pressure, App. Phys. Lett, U.S.A., August 20, 2001, Vol. 79, No. 8, pp. 1154-1156.	<input type="checkbox"/>

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